MOSPEC

S10C30 thru S10C60

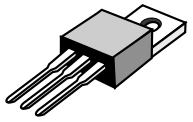
Schottky Barrier Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

* Low Forward Voltag.
* Low Switching noise.
* High Current Capacity
* Guarantee Reverse Avalance.
* Guard-Ring for Stress Protection.
* Low Power Loss & High efficiency.
* 125 °C Operating Junction Temperature
* Low Stored Charge Majority Carrier Cnduction.
* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

SCHOTTKY BARRIER RECTIFIERS

10 AMPERES
30 -- 60 VOLTS



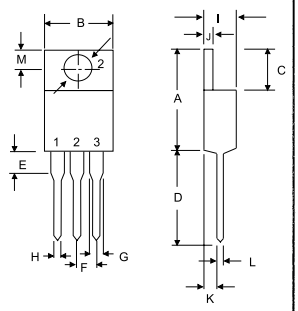
TO-220AB

MAXIMUM RATINGS

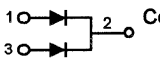
Characteristic	Symbol	S10C						Unit
		30	35	40	45	50	60	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	30	35	40	45	50	60	V
RMS Reverse Voltage	$V_{R(RMS)}$	21	25	28	32	35	42	V
Average Rectifier Forward Current Total Device (Rated V_R),T_C=100°C	$I_{F(AV)}$	5 10						A
Peak Repetitive Forward Current (Rate V_R,Square Wave,20kHz)	I_{FM}	10						A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware,single phase,60Hz)	I_{FSM}	125						A
Operating and Storage Junction Temperature Range	T_j , T_{stg}	- 65 to + 125						°C

ELECTRICAL CHARACTERISTICS

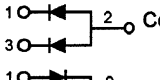
Characteristic	Symbol	S10C						Unit
		30	35	40	45	50	60	
Maximum Instantaneous Forward Voltage (I_F=5.0 Amp, T_C = 25 °C) (I_F=5.0 Amp, T_C = 100 °C)	V_F	0.55 0.47				0.65 0.55		V
Maximum Instantaneous Reverse Current (Rated DC Voltage, T_C = 25 °C) (Rated DC Voltage, T_C = 100 °C)	I_R	5.0 50						mA



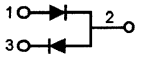
DIM	MILLMETERS	
	MIN	MAX
A	14.68	15.32
B	9.78	10.42
C	6.01	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	2.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.36
K	2.20	2.97
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90



Common Cathod
Suffix " C "



Common Anode
Suffix " A "



Double
Suffix " D "

S10C30 thru S10C45

FIG-1 FORWARD CURRENT DERATING CURVE

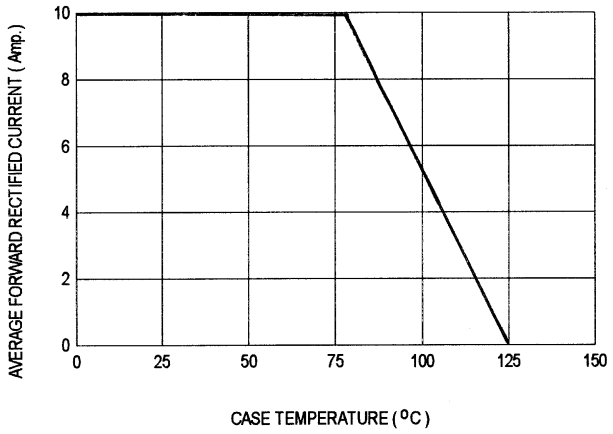


FIG-2 TYPICAL FORWARD CHARACTERISTICS

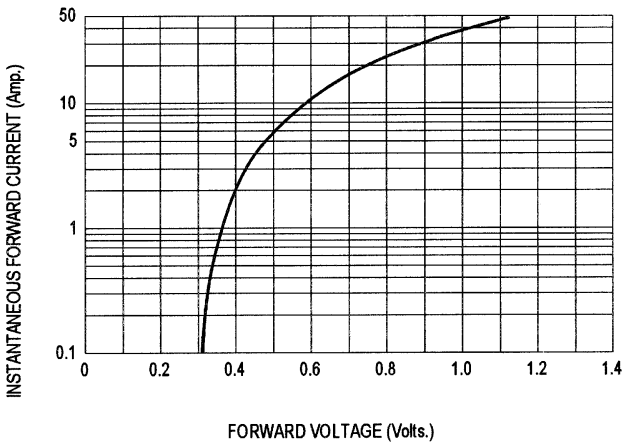


FIG-3 TYPICAL REVERSE CHARACTERISTICS

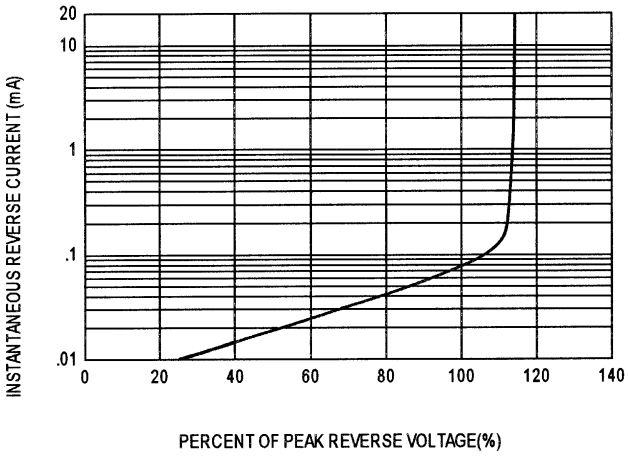


FIG-4 TYPICAL JUNCTION CAPACITANCE

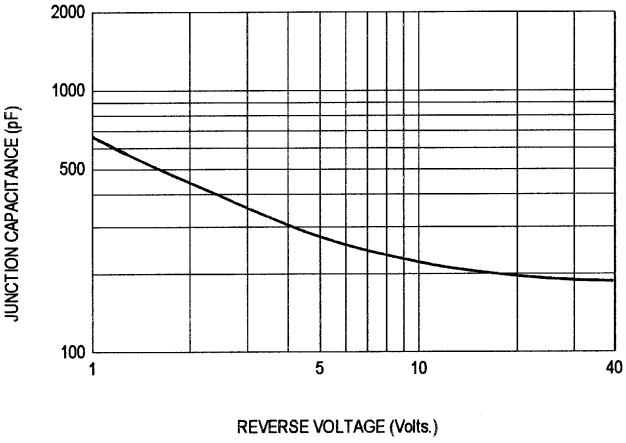


FIG-5 PEAK FORWARD SURGE CURRENT

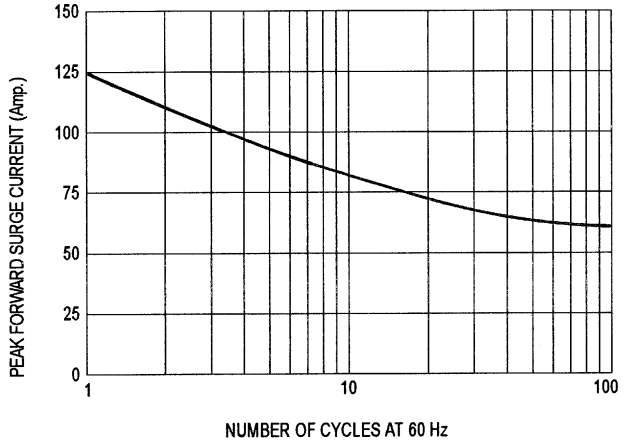


FIG-1 FORWARD CURRENT DERATING CURVE

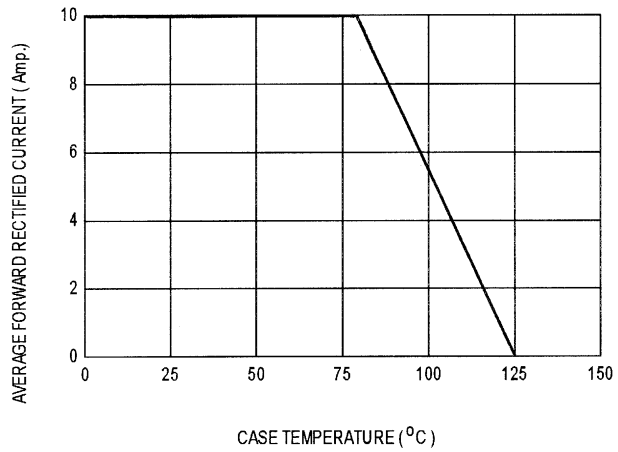


FIG-2 TYPICAL FORWARD CHARACTERISTICS

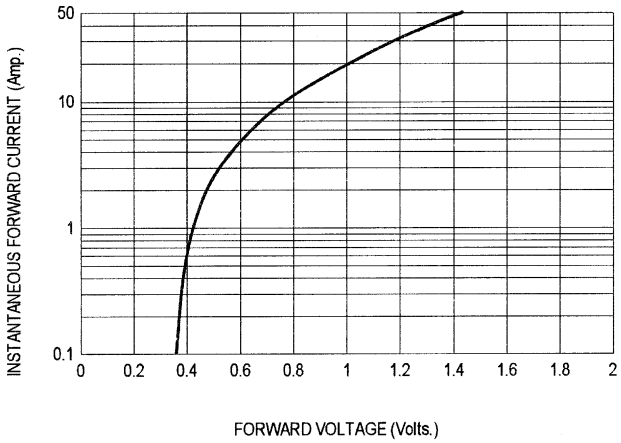


FIG-3 TYPICAL REVERSE CHARACTERISTICS

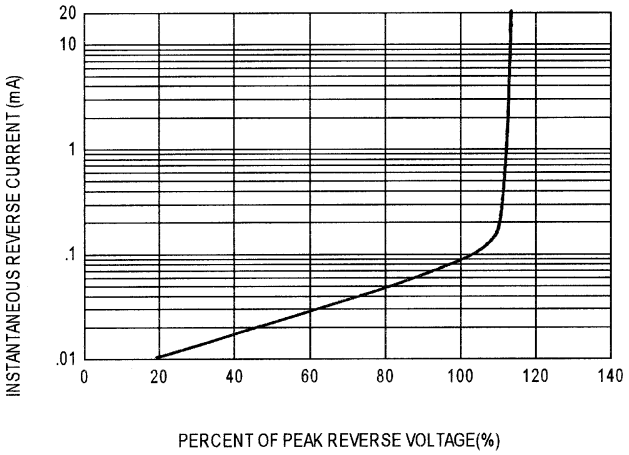


FIG-4 TYPICAL JUNCTION CAPACITANCE

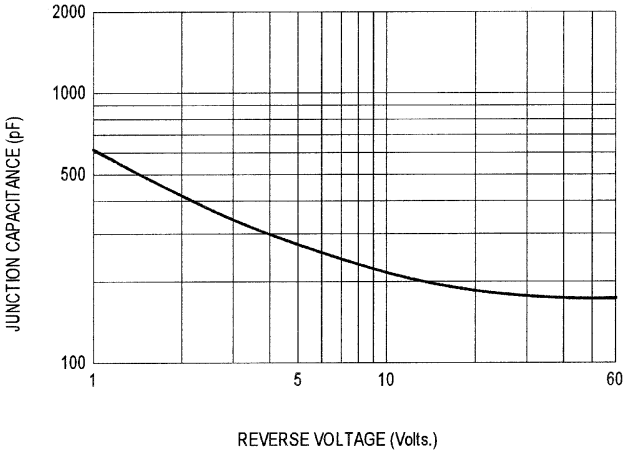


FIG-5 PEAK FORWARD SURGE CURRENT